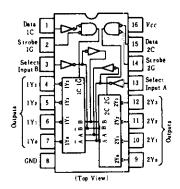
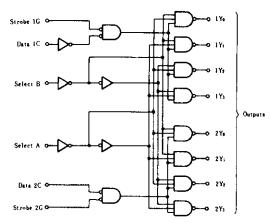
This circuit features dual 1-line-to-4-line demultiplexer with individual strobes and common binary-address inputs. When both sections are enabled by the strobes, the common binary-address inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input 1C is inverted through its outputs. The inverter following the 1C data input permits use as a 3-to-8-line decoder or 1-to-8-line demultiplexer without external gating.

■PIN ARRANGEMENT



BBLOCK DIAGRAM



■RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit
High level output voltage	Voн	_		5.5	v
Low level output current	lot	_	_	8	mA

FUNCTION TABLE

●2-to-4-line Decoder/1-to-4-line Demultiplexer

		Inputs			Outputs			Inputs			Outputs					
SEL	ECT	STROBE	DAΓA				, 		SELECT		SELECT STROBE		OBE DATA			т
В	Α	1G	1C	1Y0	1Y1	1Y2	1Y3	В	A	2G	2C	2Y0	2Y1	2Y2	2Y3	
×	×	Н	×	Н	Н	Н	Н	×	×	Н	×	н	Н	Н	н	
L	L	L	Н	I.	н	Н	Н	L	L	L	L	L	Н	Н	Н	
L	н	L	Н	Н	I.	Н	Н	L	Н	L.	L	н	L	Н	Н	
Н	L	L	Н	Н	н	L	н	н	L	L	L	Н	Н	L	Н	
Н	Н	L	Н	Н	н	Н	L	н	Н	L	L	н	н	н	L	
×	×	×	I.	Н	H	Н	н	×	×	×	Н	н	Н	Н	Н	

●3-to-8-line Decoder/1-to-8-line Demultiplexer

		Inpu	its	Outputs								
	SELECT		STROBE OR DATA	(0)	(1)	(2)	(3)	(4)	(5)	(6)	(7)	
C1)	В	Α	G ₂)	2Y0	2Y1	2Y2	2Y3	1Y0	1Y1	1Y2	1Y3	
×	×	×	Н	H	H	Н	Н	Н	Н	Н	Н	
L	L	L	L	L	Н	H	Н	Н	Н	H	H	
L	L	Н	L	Н	L	Н	Н	Н	Н	Н	Н	
L	H	L	L	Н	H	L	Н	Н	H	Н	Н	
L	Н	Н	L	Н	Н	Н	L	Н	Н	Н	Н	
Н	L	L	L	Н	Н	Н	Н	L	Н	Н	Н	
H	L	Н	L	Н	Н	Н	Н	Н	L	Н	Н	
Н	Н	L	L	Н	Н	Н	Н	Н	Н	L	Н	
Н	H	Н	L	Н	Н	Н	Н	Н	Н	H	T.	

Notes) 1. C; input 1C and 2C connected together

2. G; inputs 1G and 2G connected together

3. H; high level, L; low level, X; irrelevant

ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^{\circ}C$)

Item	Symbol	Test Conditions		min	typ*	max	Unit
	V _{tH}			2.0	_		v
Input voltage	VIL			_	-	0.8	V
Output current	Іон	$V_{CC} = 4.75V$, $V_{IH} = 2V$, $V_{IL} = 0.8V$,	-	-	100	μА	
Output voltage		V 4 7711 V 031 V 0 011	Iot = 4mA	-	_	0.4	v
	Vol	$V_{CC} = 4.75V, V_{IH} = 2V, V_{IL} = 0.8V$	Io L = 8mA			0.5	v
	Іін	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$				20	μA
Input current	lı L	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$		-	-	-0.4	mA
	Ii	$V_{CC} = 5.25 \text{V}, V_I = 7 \text{V}$		_		0.1	mА
Supply current**	Icc	$V_{CC}=5.25V$		-	6.1	10	m.A
Input clamp voltage	Vik	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$		-		-1.5	v

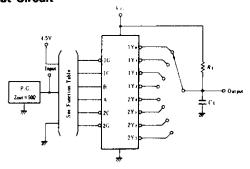
^{*} VCC=5V, Ta=25°C

ESWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

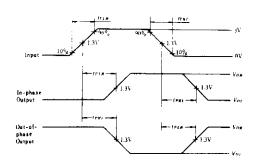
Îtem	Symbol	Inputs	Output	Level of logic	Test Conditions	min	typ	max	Unit
	telh	A, B, 2C, 1G or 2G	Y	2		_	25	40	
	tphl.	A, B, 2C, 1G or 2G	Y	2	$C_L = 15 \mathrm{pF},$ $R_L = 2 \mathrm{k} \Omega$	_	34	51	
	tpl.H	A or B	Y	3		_	31	46	
Propagation delay time	tPHL	A or B	Y	3		_	34	51	ns
	tPLH	1C	Y	3			-	32	48
	tphl.	1C	Y	3			32	48	1

ETESTING METHOD

1) Test Circuit



Waveform



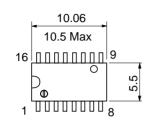
Notes) 1. Input pulse; $t_{TL,H} \le 15$ ns, $t_{TH,L} \le 6$ ns, PRR = 1MHz, duty cycle=50%.

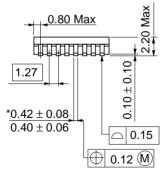
2. C_L includes probe and jig capacitance.

^{**} I_{CC} is measured with outputs open, A, B, and 1C inputs at 4.5V, and 2C, 1G, and 2G inputs grounded.

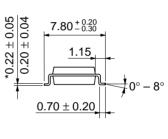
Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min $0.25^{+0.13}_{-0.05}$ 0.48 ± 0.10 2.54 ± 0.25 $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm





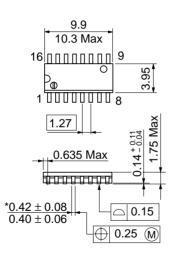


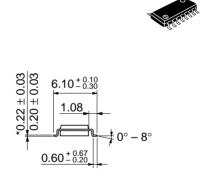


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 a

*Dimension including the plating thickness
Base material dimension

Unit: mm





*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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